



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **KANO, Takashi et al.**

28/28  
#5  
12-11-02  
Moulis

Serial No.: 09/941,982

Group Art Unit: 2812

Filed: August 30, 2001

Examiner: **MULPURI, Savitri**

P.T.O. Confirmation No.: 7536

For. **METHOD OF FORMING NITRIDE-BASED SEMICONDUCTOR LAYER, AND  
METHOD OF MANUFACTURING NITRIDE-BASED SEMICONDUCTOR  
DEVICE**

**PETITION FOR EXTENSION OF TIME**

Commissioner for Patents  
Washington, D.C. 20231

Date: November 27, 2002

Sir:

Applicants petition the Commissioner for Patents to extend the time for response to the Office Action dated June 28, 2002 for two months from September 28, 2002 to November 28, 2002.

Attached please find a check in the amount of \$400.00 to cover the cost of the extension for a large entity. In the event that any additional fees are due in connection with this paper, please charge our Deposit Account No. 01-2340. Two copies of this paper are enclosed herewith.

12/02/2002 MAHMED1 00000031 09941982

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400.00 OP

Respectfully submitted,

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